

UNITED STATES PATENT AND TRADEMARK OFFICE
CERTIFICATE OF CORRECTION

PATENT NO. : 7,560,958 B1
APPLICATION NO. : 10/619169
DATED : July 14, 2009
INVENTOR(S) : Francisco Javier Guerrero Mercado

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Page 1 of 1

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

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Delete the title page and substitute therefor the
attached title page showing the corrected number
of Drawing Sheets in patent.

Delete Drawing Sheets 1-4 and substitute therefor
the attached Drawing Sheets 1-2. ~~amending~~ ~~or~~

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(12) **United States Patent**
Guerrero Mercado

(10) **Patent No.:** **US 7,560,958 B1**
(45) **Date of Patent:** **Jul. 14, 2009**

(54) **LOW POWER COMPARATOR WITH FAST PROPAGATION DELAY**

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(*) Notice: Subject to any disclaimer, the term of this patent is extended or adjusted under 35 U.S.C. 154(b) by 1066 days.

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H03K 5/22 (2006.01)

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(58) Field of Classification Search **327/52, 327/53, 54, 56, 58, 63, 65, 66, 67, 72, 77-79, 327/80, 81, 88, 89**

See application file for complete search history.

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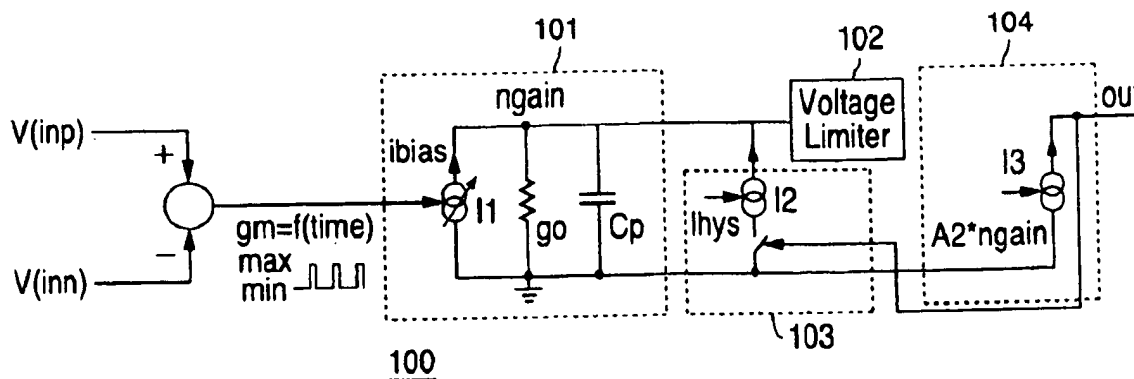
* cited by examiner

Primary Examiner—Tuan Lam

(57) **ABSTRACT**

A direct relationship exists between an integrated comparator's propagation delay and the input differential pair's bias current and overdrive voltage. A new method using a pulsed bias scheme for the input differential pair improves propagation delay by more than one order of magnitude without increasing significantly the average quiescent current, as long as the pulse width of the bias current is small relative to the system clock. A voltage limiter optimizes the comparator's transition time and a built-in hysteresis circuit minimizes spurious output transitions whenever the pulsed bias current pulse changes state. The bias current pulse and sampling of the comparator occur in predefined relation to the system clock.

20 Claims, 2 Drawing Sheets



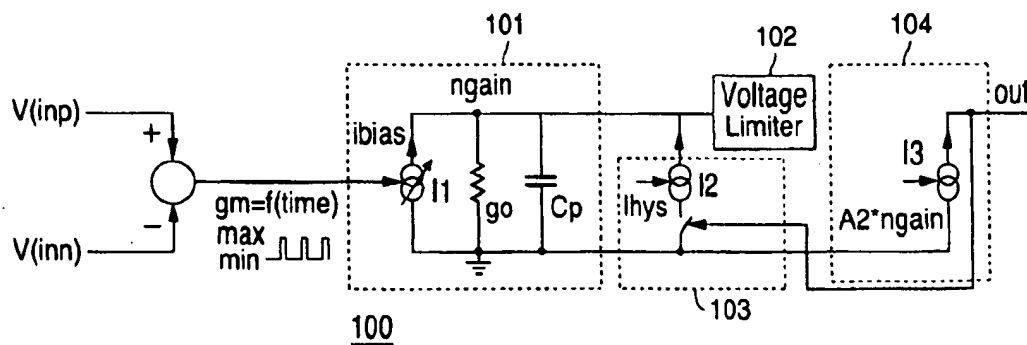


FIG. 1

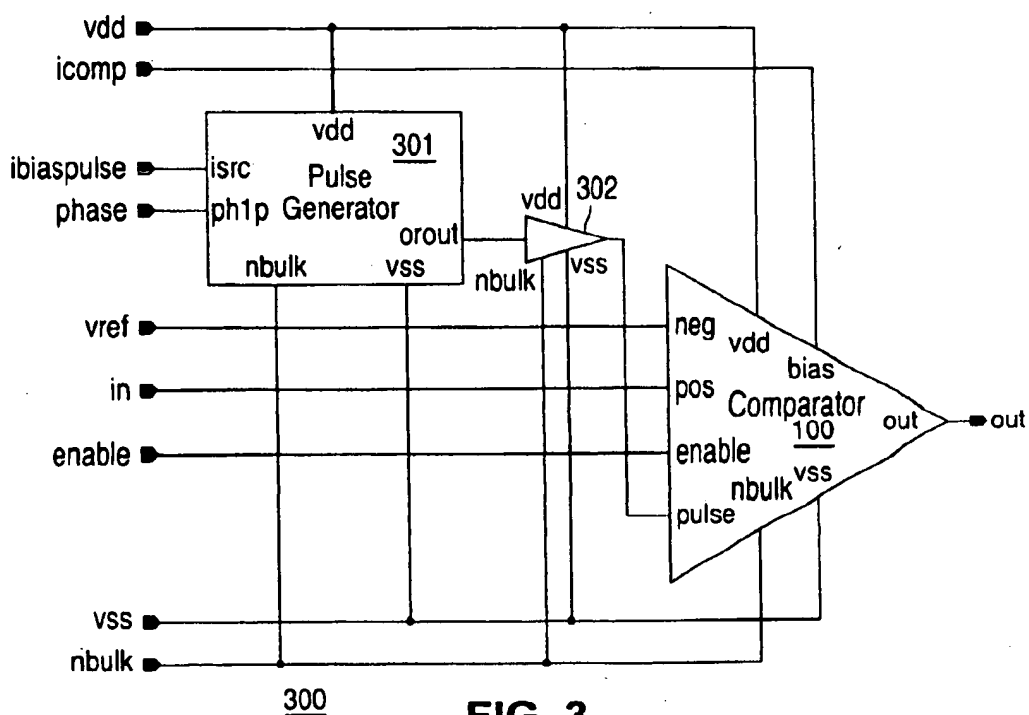


FIG. 3

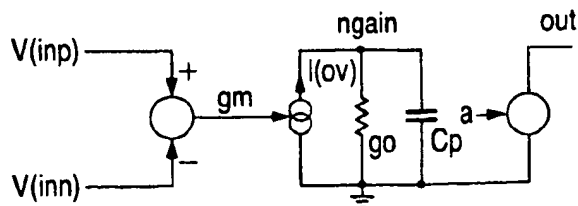
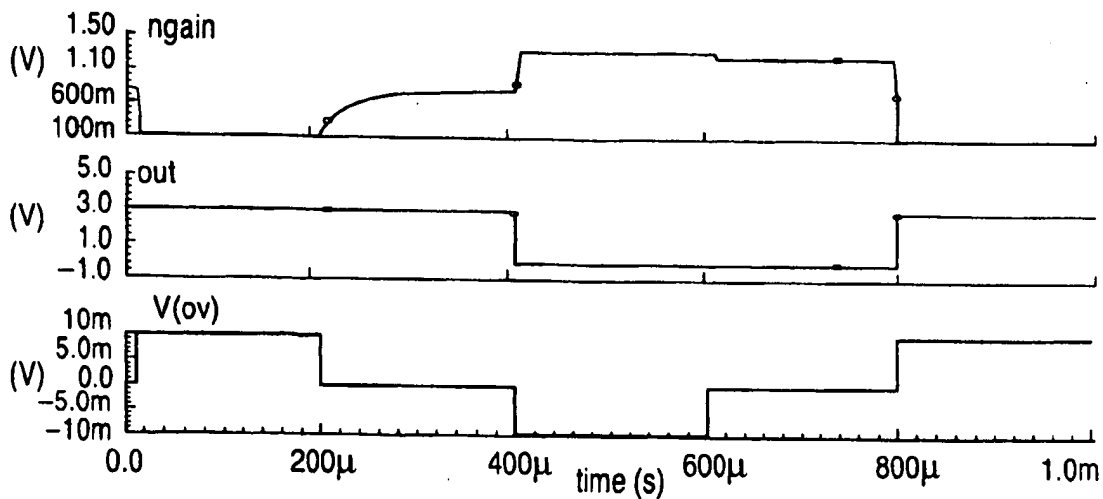
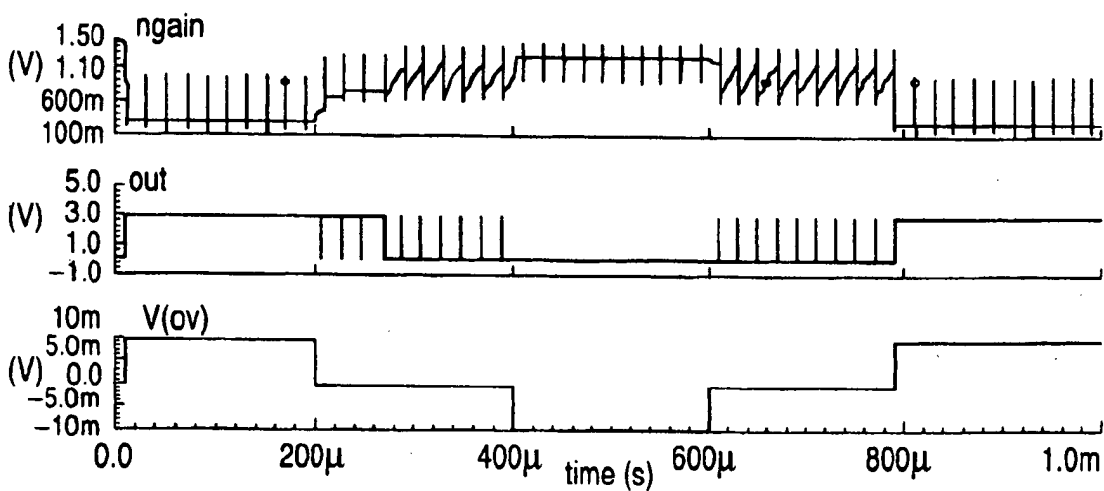
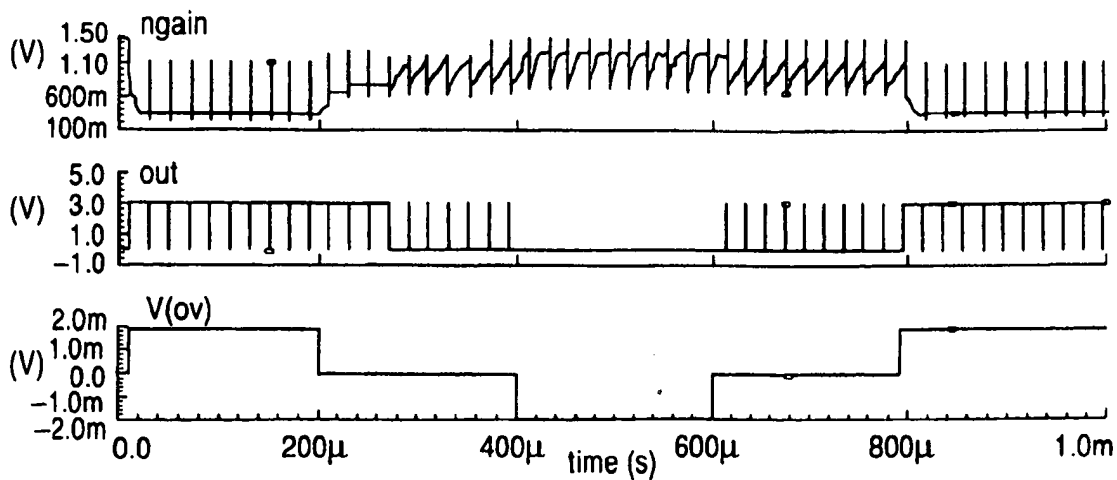


FIG. 4

**FIG. 2A****FIG. 2B****FIG. 2C**